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<u>Fairchild Semiconductor</u> <u>P1087</u>

For any questions, you can email us directly: sales@integrated-circuit.com



Datasheet of P1087 - JFET P-CH 30V 350MW TO92 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



P1087

P-Channel Switch

- This device is designed for low level analog switching sample and hold circuits and chopper stabilized amplifiers.
- · Sourced from process 88.



Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V_{DG}	Drain-Gate Voltage	- 30	V	
V _{GS}	Gate-Source Voltage	30	V	
I _{GF}	Forward Gate Current	50	mA	
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ +150	°C	

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- These ratings are based on a maximum junction temperature of 150 degrees C.
 These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition		Min.	Тур.	Max.	Units
BV _{GSS}	Gate-Source Breakdown Voltage	$V_{DS} = 0V$, $IG = 1\mu A$		30			V
I _{GSS}	Gate Reverse Current	V _{GS} = 15V				2	nA
I _D (off)	Drain Cutoff Leakage Current	V _{DS} = 15V				10	nA
		$V_{GS} = 7V$	T = +85°C			0.5	μΑ
I _{DGO}	Drain-Gate Leakage Current	V _{DG} = 15V				2	NΑ
		I _S = 0	T = +85°C			0.1	μΑ
I _{DSS}	Zero-Gate Voltage Drain Current	V _{DS} = 20V, V _{GS} = 0V		5			mA
V _{GS} (off)	Gate-Source Cutoff Voltage	V _{DS} = 15V, I _D = 1μA				5	V
V _{DS} (on)	Drain-Source On Voltage	$V_{GS} = 0V$, $I_D = 3mA$				0.5	V
r _{DS} (on)	Drain-Source On Resistance	$V_{GS} = 0V$, $I_D = 1mA$				150	Ω
r _{ds} (on)	Drain-Source On Resistance	$V_{GS} = 0V, I_{D} = 0, f = 1kHz$				150	Ω
C _{iss}	Input Capacitance	V _{DS} = 15V, V _{GS} = 0V, f = 1MHz				45	pF
C _{rss}	Reverse Transfer Capacitance	V _{DS} = 0V, V _{GS} = 7V, f = 1MHz				10	pF
t _d (on)	Trun On Time	$V_{DD} = -6V$ $V_{GS}(off) = +7V$ $R_{L} = 1.8k\Omega$ $I_{D}(on) = -3mA$				15	ns
t _r	Rise Time					75	ns
t _d (off)	Trun Off Time					25	ns
t _f	Fall Time					100	ns

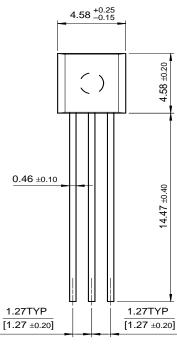
Thermal Characteristics TA=25°C unless otherwise noted

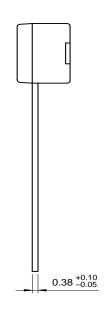
Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

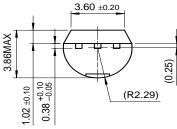


Package Dimensions









Dimensions in Millimeters

Distributor of Fairchild Semiconductor: Excellent Integrated System Limited Datasheet of P1087 - JFET P-CH 30V 350MW TO92

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Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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